NSN 5961-01-150-8699

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-150-8699 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.450 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case: Component Name And Quantity:** 2 transistor **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 45.0 reverse voltage, instantaneous all transistor **Current Rating Per Characteristic:** 30.00 amperes forward current, average all transistor **Power Rating Per Characteristic:** 1.4 watts small-signal input power, common-collector preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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